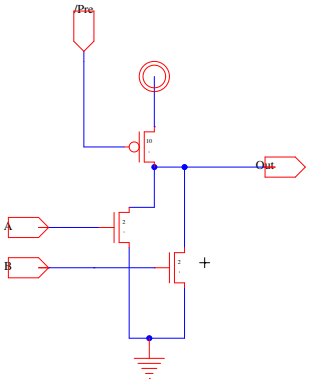
Assume: velocity saturated, $R_0/2$ sizing for gate drive; inverter sizing is: W_n=W_p=2

1. Consider:



(a) if A=B=0 and /pre is 0, what voltage does Out hold?

(b) if /pre switches from 0 to 1, and A=B=0, what voltage settles on Out?

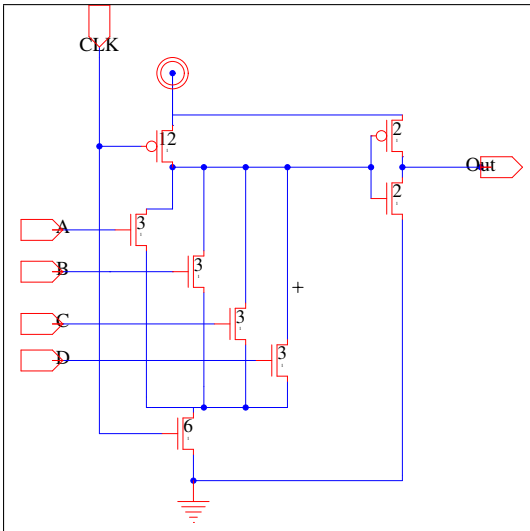
(c) if /pre is at 1 and, B switches from 0 to 1 what voltage settles on Out?

(d) What are the sizing constraints on the NMOS devices (compare to ratioed logic)?

(e) What concerns might we have with this logic?

(f) What requirements must we satisfy for correct operation?

2. Determine delays (express in τ units in terms of γ):

	Precharge	Drive Input	Drive Inv. and Self Output
	(pullup transistor charging inverter)		
	—	Input	Self Output Delay